

Features

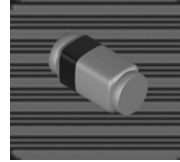
- Silicon Epitaxial Planar Diodes
- Electrical data identical with the devices 1N4148 and 1N4448 respectively
- Quadro Melf package

Applications

- Extreme fast switches

Mechanical Data

- Case:QuadroMELF Glass Case (SOD-80)
- Weight: approx. 34 mg
- Cathode Band Color: Black



Absolute Maximum Ratings

($T_{amb}=25^{\circ}\text{C}$ unless otherwise specified)

Parameter	Test Condition	Symbol	Value	Unit
Repetitive peak reverse voltage		V_{RRM}	100	V
Reverse voltage		V_R	75	V
Peak forward surge current	$t_p = 1 \mu\text{s}$	I_{FSM}	2	A
Repetitive peak forward current		I_{FRM}	500	mA
Forward current		I_F	300	mA
Average forward current	$V_R=0$	I_{FAV}	150	mA
Power dissipation		P_V	500	mW

Thermal Characteristics

($T_{amb}=25^{\circ}\text{C}$ unless otherwise specified)

Parameter	Test Condition	Symbol	Value	Unit
Junction ambient	on PC board 50 mm X 50mm X 1.6mm	$R_{\theta JA}$	500	K/W
Junction temperature		T_J	175	$^{\circ}\text{C}$
Storage temperature range		T_{stg}	-65 to +175	$^{\circ}\text{C}$

Electrical Characteristics

($T_{amb}=25^{\circ}\text{C}$ unless otherwise specified)

Parameter	Test Condition	Part	Symbol	Min.	Typ.	Max.	Unit
Forward voltage	$I_F=5\text{mA}$	LS4448	V_F	0.62		0.72	V
	$I_F=50\text{mA}$	LS4148			0.86	1	
	$I_F=100\text{mA}$	LS4148			0.93	1	
Reverse current	$V_R=20\text{V}$		I_R			25	nA
	$V_R=20\text{V}, T_J=150^{\circ}\text{C}$		I_R			50	μA
	$V_R=75\text{V}$		I_R			5	μA
Breakdown voltage	$I_R=100\mu\text{A}, t_p/T=0.01, t_p=0.3\text{ms}$		$V_{(BR)}$	100			V
Diode capacitance	$V_R=0, f=1\text{MHz}, V_{HF}=50\text{mV}$		C_D			4	pF
Rectification efficiency	$V_{HF}=2\text{V}, f=100\text{MHz}$		η_r	45			%
Reverse recovery time	$I_F=I_R=10\text{mA}, i_R=1\text{mA}$		t_{rr}			8	ns
	$I_F=10\text{mA}, V_R=6\text{V}, i_R=0.1 \times I_{FR}, R_L=100\Omega$					4	

■ Typical characteristics

($T_{amb} = 25^{\circ}\text{C}$ unless otherwise specified)

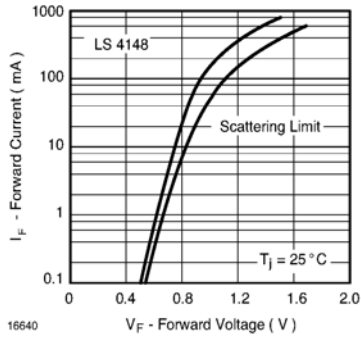


Fig. 1 Forward Current vs. Forward Voltage

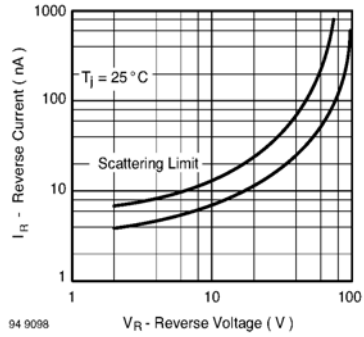


Fig. 3 Reverse Current vs. Reverse Voltage

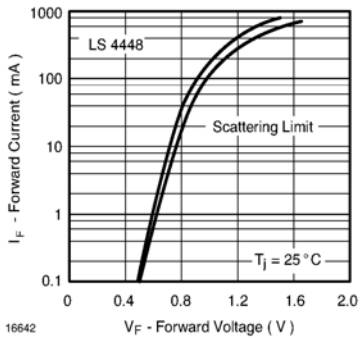


Fig. 2 Forward Current vs. Forward Voltage

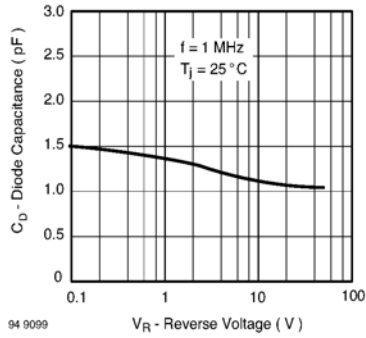
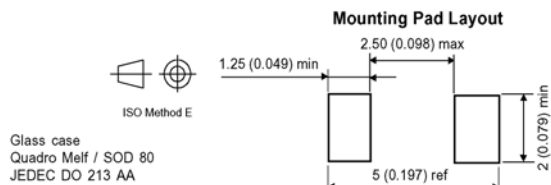
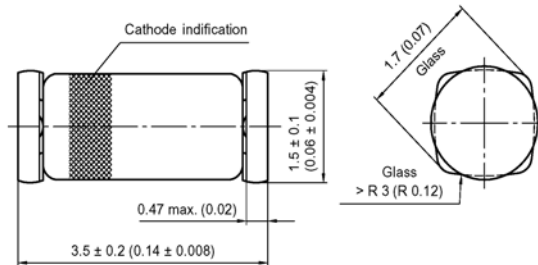


Fig. 4 Diode Capacitance vs. Reverse Voltage

Package Dimensions in mm (inches)



Glass case
 Quadro Melf / SOD 80
 JEDEC DO 213 AA